AMENDMENTS TO THE SPECIFICATION

IN THE SPECIFICATION:

Paragraph [042] on page 11 has been amended as follows:

[042] Fig. 5 is a sectional view of an organic EL device, according to an embodiment of the present invention;

Paragraph [043] on page 11 has been amended as follows:

[043] Fig. 6 is a detailed block diagram of a part of an organic EL device, according to an embodiment of the present invention; and

Paragraph [044] on page 11 has been amended as follows:

[044] Fig. 7 is a flow chart illustrating a fabricating method of an organic EL device, according to an embodiment of the present invention.

Paragraph [046] on pages 11-12 has been amended as follows:

[046] Fig. 5 illustrates a sectional view of an organic EL device, according to an embodiment of the present invention. The organic EL device shown in Fig. 5 includes an organic EL array 150 having a thin film transistor (TFT) array portion 114 formed on the upper part of a transparent substrate 102, and an EL layer 160 formed on the thin film transistor (TFT) array portion 114.

The EL layer 160 includes a first electrode 104 (or an anode), an organic EL layer 110, and a second electrode 100 (or a cathode). The EL layer 160 further includes a dielectric layer 115 (see Fig. 63).

Paragraph [050] on page 12 has been amended as follows:

[050] An absorptive material or getter 172 is filled into an etched portion of the packaging plate 128. ~~the~~ The absorptive material or getter 172 is fixed in place by a selective transparent film 125.